# MCR265-4 Series

Preferred Device

# Silicon Controlled Rectifiers

# **Reverse Blocking Thyristors**

Designed for inverse parallel SCR output devices for solid state relays, welders, battery chargers, motor controls or applications requiring high surge operation.

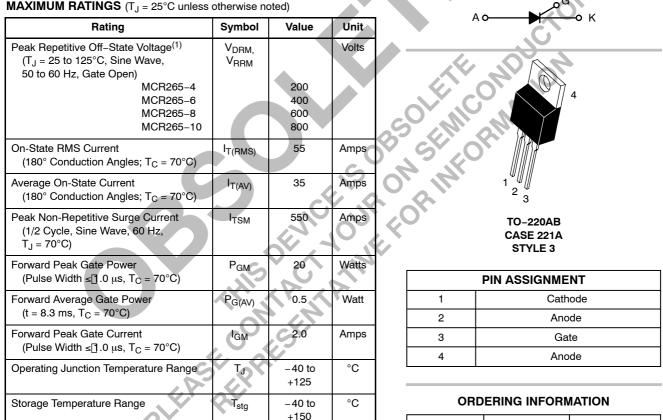
- Photo Glass Passivated Blocking Junctions for High Temperature Stability, Center Gate for Uniform Parameters
- 550 Amperes Surge Capability
- Blocking Voltage to 800 Volts
- Device Marking: Logo, Device Type, e.g., MCR265-4, Date Code



### **ON Semiconductor**

http://onsemi.com

## SCRs **55 AMPERES RMS** 200 thru 800 VOLTS



(1) V<sub>DBM</sub> and V<sub>BBM</sub> for all types can be applied on a continuous basis. Ratings apply for zero or negative gate voltage; however, positive gate voltage shall not be applied concurrent with negative potential on the anode. Blocking voltages shall not be tested with a constant current source such that the voltage ratings of the devices are exceeded.

These devices are rated for use in applications subject to high surge conditions. Care must be taken to insure proper heat sinking when the device is to be used at high sustained currents.

TO220AB Preferred devices are recommended choices for future use and best overall value.

Package

TO220AB

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Device

MCR265-4

MCR265-6

MCR265-8

MCR265-10

Shipping

500/Box

500/Box

500/Box

500/Box

## MCR265-4 Series

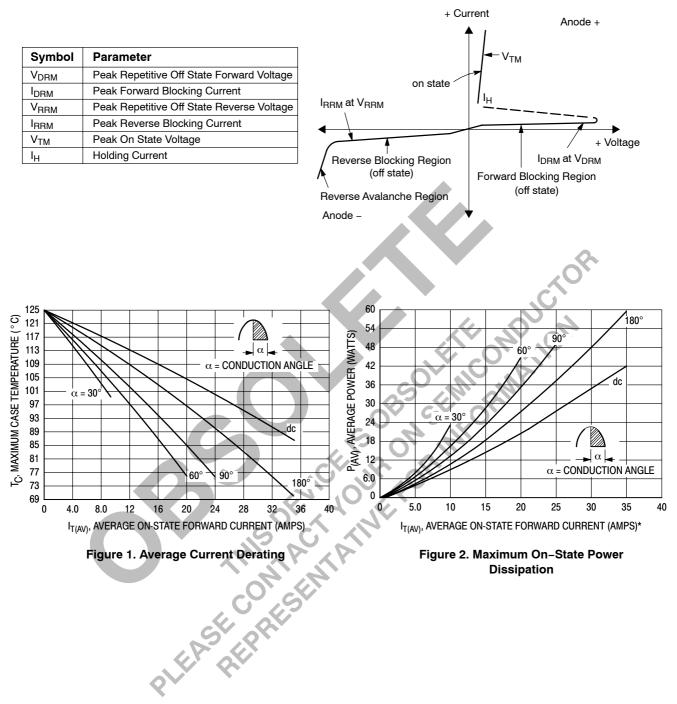
#### THERMAL CHARACTERISTICS

Characteristic		S	ymbol	Max		Unit	
Thermal Resistance, Junction to Case			$R_{\theta JC}$	0.9	c	°C/W	
Thermal Resistance, Junction to Ambient			$R_{\theta JA}$	60	c	°C/W	
Maximum Lead Temperature for Soldering Purposes 1/8" from Case for 10 Seconds		s	TL	260		°C	
<b>ELECTRICAL CHARACTERISTICS</b> ( $T_C = 25^{\circ}C$ unless other the second state of the se	nerwise noted.)						
Characteristic		Symbol	Min	Тур	Max	Unit	
OFF CHARACTERISTICS							
	J = 25°C J = 125°C	<sub>RM</sub> , I <sub>RRM</sub>			10 2.0	μA mA	
ON CHARACTERISTICS							
Peak Forward On-State Voltage <sup>(1)</sup> (I <sub>TM</sub> = 110 A)		V <sub>TM</sub>		1.5	1.9	Volts	
Gate Trigger Current (Continuous dc) $(V_{AK} = 12 \text{ Vdc}, R_L = 100 \text{ Ohms})$ $(T_C = -40^{\circ}\text{C})$		J <sub>GT</sub>	_	20 40	50 90	mA	
Gate Trigger Voltage (Continuous dc) (V <sub>AK</sub> = 12 Vdc, R <sub>L</sub> = 100 Ohms)		V <sub>GT</sub>	_	1.0	1.5	Volts	
Gate Non-Trigger Voltage $(V_{AK} = 12 \text{ Vdc}, R_L = 100 \text{ Ohms}, T_J = 125^{\circ}\text{C})$		V <sub>GD</sub>	0.2	. 40	_	Volts	
Holding Current (V <sub>AK</sub> = 12 Vdc, Initiating Current = 200 mA, Gate Open)		lμ		30	75	mA	
Turn-On Time (I <sub>TM</sub> = 55 A, I <sub>GT</sub> = 200 mAdc)	010	t <sub>gt</sub>	Q.	1.5	_	μs	
DYNAMIC CHARACTERISTICS	19 C						
Critical Rate-of-Rise of Off-State Voltage	C A	dv/dt	_	50		V/μs	

DYNAMIC CHARACTERISTICS	
Critical Rate-of-Rise of Off-State Voltage dv/dt - 50 - V/	/μs
(1) Pulse Width ≤ 300 μs, Duty Cycle ≤ 2%.	

### MCR265-4 Series

#### Voltage Current Characteristic of SCR



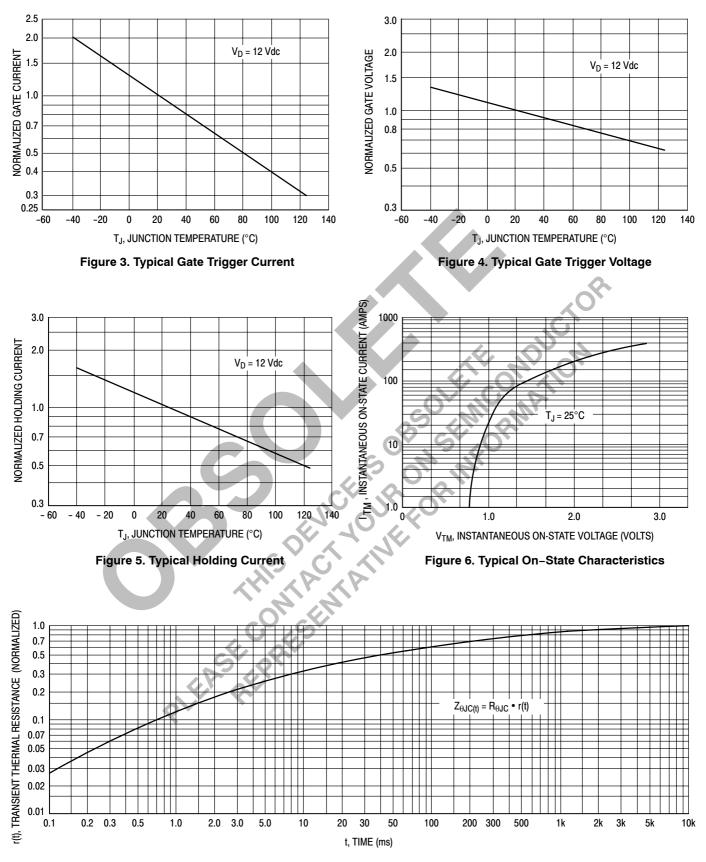
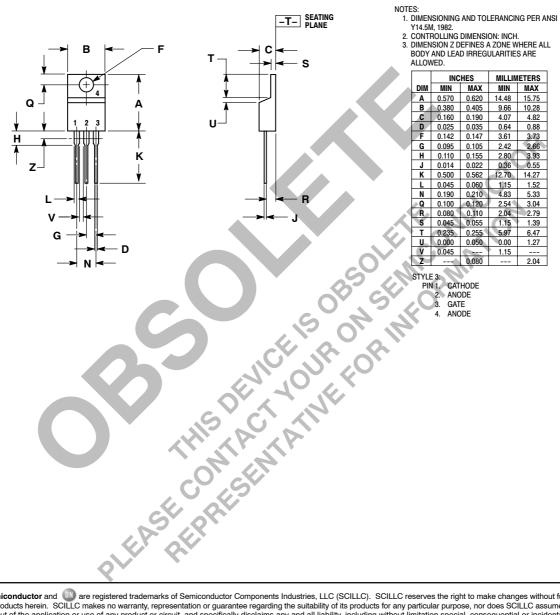


Figure 7. Thermal Response

#### PACKAGE DIMENSIONS

TO-220AB CASE 221A-07 ISSUE Z



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